

Technical field

5 The invention relates to a reflection-free termination of a TEM waveguide, in which a TEM wave is conducted through an inner conductor and an outer conductor and is absorbed at one end of the TEM waveguide by an RF absorber for absorbing the field energy and by an ohmic line termination for absorbing the conductor-guided energy of the TEM wave.

Prior art

10 A device for EMI testing electronic equipment is known from Patent Application EP-A1-0 246 544. Compared with other test equipment, it exhibits great advantages in EMI testing (EMI = electromagnetic interference) electronic equipment. In particular, it creates a defined
15 field distribution over a wide frequency range and can also be used for wide-band emission measuring.

20 However, it has been found that unwanted local and frequency-dependent inhomogeneities occur in the wave field. This is associated with the fact that the line termination is not sufficiently free of reflections.

25 A line termination for TEM waveguides is known, for example, from Offenlegungsschrift DE-31 30 487 A1. In particular, the inner conductor is there provided with terminating resistors which are located on equipotential lines, that is to say across the direction of propagation of the wave field. Measurements with such arrangements have shown, however, that these are not suitable for frequencies above 100 MHz.

Presentation of the invention

30 The object of the invention is to provide a reflection-free termination of a TEM waveguide of the type initially mentioned.

35 According to the invention, the solution consists in the fact that in such a line termination for TEM waveguides

- a) the line termination is located in a plane determined by the inner conductor and located in the

- wave direction,
- b) the line termination is constructed as an ohmic resistance which produces a gradual, serial damping on the inner conductor and
 - 5 c) locally compensates for a capacitance loading additionally produced at the line termination by the RF absorbers.

The field energy is absorbed in an absorber area arranged in parallel with the ohmic termination.

10 The line termination preferably at the same time exhibits a resistance contour which matches the current distribution across the direction of propagation of the TEM wave.

15 It is particularly advantageous to use the line termination according to the invention in a device for EMI testing electronic equipment, the device comprising a pyramidally expanding TEM waveguide which is terminated by a field-matching spherical-cap-shaped RF absorber with RF point absorbers.

20 This enables the electronic equipment to be not only reliably tested for irradiation but also their emission to be accurately measured.

Further advantageous embodiments of the invention are found in the dependent claims.

25 **Brief description of the drawings**

In the text which follows, the invention will be explained in greater detail with reference to illustrative embodiments and in conjunction with the drawing, in which:

30 Fig. 1 shows a device for EMI testing electronic equipment; and

Fig. 2 shows a line termination according to the prior art;

35 Fig. 3 shows a line termination according to the invention; and

Fig. 4 shows a line termination in the form of a discrete resistance network.

Ways of implementing the invention

Fig. 1 shows the essential parts of a device for EMI testing electronic equipment. It comprises a TEM waveguide with an outer conductor 1, an unbalanced inner conductor 4, a feeder wedge 2 and an RF absorber 5. A coaxial cable 3 supplies, for example, a pulse-shaped or sinusoidal radio frequency (RF) to the feeder wedge 2 which generates a TEM wave (TEM = transverse electromagnetic) and couples it into the TEM waveguide.

The TEM waveguide expands pyramidally from a point. The RF absorber 5 is located at the expanded end of the TEM waveguide and has the shape of a spherical cap. It is provided with RF point absorbers 6 and matched to the required wave field propagating in the TEM waveguide. That is to say, it absorbs the field proportion of the energy of the TEM wave.

The TEM waveguide as such is described in detail in Swiss Patent Application CH-2026/86-9 the content of which is herewith included in the present application.

The inner conductor 1 is plate-shaped and is provided with a line termination 7 at the wide end of the TEM waveguide 1. According to the invention, this line termination 7 is constructed in such a manner that the conductor-guided proportion of the energy of the TEM wave is absorbed. This line termination cannot produce any interference and, at the same time, interference modes produced for other reasons are attenuated. In the text which follows, the essential points to be noted in order to obtain the desired effects are discussed.

Firstly, the line termination 7 must be geometrically arranged in such a manner that it is located in a plane determined by the inner conductor 4. It thus represents a level continuation of the inner conductor 4 in the direction of the wave field. (An arrow designated by z indicates the direction of the wave field in Fig. 1.) Thus, a current flowing in the inner conductor 4 is removed without discontinuity. Due to the fact that the current propagation in the wave direction is not disturbed, no unwanted modes are produced.

Secondly, the line termination 7 must be constructed as an ohmic resistance which produces a gradual serial damping on the inner conductor 4. This will be explained with reference to Figures 2 and 3.

5 Fig. 2 shows how the inner conductor 4 is terminated in the prior art. (Figures 2 and 3 show a top view of the area of the inner conductor 4.) The wave field generated is attenuated in an end region T which is given by the thickness of the RF absorber 5. In this end
10 region, the inner conductor 4 is contoured in the form of teeth and ends at the point where the RF point absorbers 6 abut one another. The tooth points are passed through the coherent part of the RF absorber 5 by means of a wire and are terminated with an ohmic resistance R behind it.

15 Fig. 3 shows how the line termination 7 according to the invention terminates the inner conductor 4. The RF absorber 5 and an RF point absorber 6 are indicated as in Fig. 2. The line termination 7 covers the entire end
20 region T. It thus also passes through the coherent part of the RF absorber 5. It is constructed as an area and has a resistance contour dR/dz , in the direction of propagation of the wave field, which locally compensates for the capacitance loading additionally produced at the line termination 7 by the RF absorber 5. The TEM wave
25 thus "sees" the locally matched characteristic impedance at any point.

In the general case, the resistance contour dR/dz rises from a small value at the inner conductor/line termination transition to a maximum and then falls again
30 to a small value towards the end of the end region.

According to a preferred embodiment of the invention, the line termination exhibits at the same time a resistance contour which matches the current distribution across the direction of propagation of the TEM wave.
35 This prevents the large current components at the lateral edge of the inner conductor from being dispersed across the direction of propagation of the TEM wave. Correspondingly, the resistance contour decreases across the direction of the wave field, that is to say from the

center of the line termination towards the sides. Seen quantitatively, the resistance contour will thus have the smallest values at the edges of the line termination.

5 Finally, the line termination 7 is constructed in such a manner that a capacitance loading additionally produced at the inner conductor 4 by the RF absorber 5 and the RF point absorber 6 is locally compensated.

10 The line termination 7 according to the invention can be preferably implemented in such a manner that a support plate, for example a plywood plate, is provided with a resistance layer, for example graphite coating with suitable location-dependent thickness. So that the current is conducted preferably without interference from the inner conductor 4 to the resistance coating, a
15 metallic tooth-shaped transition region can be provided on the support plate.

20 Fig. 4 shows a further embodiment. In this embodiment, the ohmic serial damping on the line termination is implemented by means of a network of discrete resistors.

 A fibre-reinforced plastic plate is suitable as support plate. It is covered with a suitable resistance layer or is itself used directly as resistance, depending on material.

25 However, the invention is not restricted to the illustrative embodiments described. In particular, it is also suitable for open or half-open TEM waveguides in which therefore the outer conductor is open at one or several ends.

30 In the text which follows, further characteristics and advantages of the invention are listed as keywords:

- 35
1. The invention creates a distinct increase in quality with respect to the field homogeneity in the entire test volume and frequency range.
 2. It is thus possible to construct much larger high-quality test chambers (for example for systems and vehicles).

3. The production costs of the terminating area of wide-band cells are lowered.
4. Compared with the discrete resistors in the prior art, the cooling of the terminating resistance distributed over an area is better and more simple. Correspondingly, the test chambers can be used for higher operating field strengths. Similarly, a greater constructional height is made possible by this.
5. The high-voltage strength becomes greater.
6. Due to the high field quality, a precise correlation with the standardised free-field emission values is possible.
7. The invention can also be used for terminating open waveguide arrangements.
8. Finally, wide-band, high-power and high-voltage-resistant terminating loads (so-called dummy loads) can be constructed in accordance with the invention.

It can be said in conclusion that the invention creates a wide-band reflection-free line termination which can be used with great advantage wherever high power has to be dissipated.

PATENT CLAIMS

1. Reflection-free termination of a TEM waveguide, in which a TEM wave is conducted through an inner conductor (4) and an outer conductor (1) and is absorbed at one end of the TEM waveguide by an RF absorber (5) for absorbing a field energy and by an ohmic line termination (7) for absorbing a conductor-guided energy of the TEM wave, characterised in that

a) the line termination (7) is located in a plane determined by the inner conductor (4) and located in the wave direction,

b) the line termination (7) is constructed as an ohmic resistance which produces a gradual, serial damping on the inner conductor (4) and

c) locally compensates for a capacitance loading additionally produced at the line termination (7) by the RF absorber (5).

2. Reflection-free termination of a TEM waveguide according to Claim 1, characterised in that the TEM waveguide is a closed TEM waveguide.

3. Reflection-free termination of a TEM waveguide according to Claim 1, characterised in that the TEM waveguide is an open TEM waveguide.

4. Reflection-free termination of a TEM waveguide according to Claim 1, characterised in that the line termination (7) comprises a support plate with a resistance layer.

5. Reflection-free termination of a TEM waveguide according to Claim 1, characterised in that the line termination comprises a network of discrete resistors.

6. Reflection-free termination of a TEM waveguide according to Claim 4, characterised in that the resistance layer consists of graphite and exhibits a location-dependent thickness.

7. Reflection-free termination of a TEM waveguide according to Claim 4, characterised in that the support plate is a fibre-reinforced plastic plate.

8. Reflection-free termination of a TEM waveguide according to Claim 1, characterised in that the line

termination is formed by a fibre-reinforced plastic plate.

5 9. Reflection-free termination of a TEM waveguide according to Claim 1, characterised in that the line termination, at the same time, exhibits a resistance contour which matches a current distribution across the direction of propagation of the TEM wave.

10 10. Device for EMI testing electronic equipment by means of a pyramidally expanding TEM waveguide which is terminated by a field-matched spherical-cap-shaped RF absorber (5) with RF point absorbers (6) and which exhibits a plate-shaped inner conductor (4) with a line termination (7), characterised in that

15 a) the line termination (7) is located in a plane determined by the inner conductor (4) and located in the wave direction,

b) the line termination (7) is constructed as an ohmic resistance which produces a gradual, serial damping on the inner conductor (4) and

20 c) locally compensates for a capacitance loading additionally produced at the line termination (7) by the RF absorber (5)